



# ST49C101A-XX

## High Frequency Clock Multiplier

January 1999 -3

### FEATURES

- Mask Programmable Analog Phase Locked Loop
- Up to 200MHz Operation
- Preprogrammed Multiplication Factors of 2, 3, 4, 5, 6, 8, 10 and 12X
- Low Output Jitter
- Replace Expensive High Frequency Oscillator
- Crystal Oscillator Circuit On Chip
- Low Power Single Supply 5V or 3.3V CMOS Technology
- Small 8 Lead SOIC Package

### APPLICATIONS

- Voltage Controlled Crystal Oscillator (VCXO)
- System Clock Multiplication in:
  - Computer Systems
  - Telecommunications Systems
  - Set-top Boxes

### GENERAL DESCRIPTION

The ST49C101A-XX is a mask programmable monolithic analog phase locked loop device, designed to replace existing high frequency crystal oscillator with a low frequency crystal. The high performance

ST49C101A-XX provides low jitter clock output and operates up to 180 MHz. at 3.3 volts power supply. The ST49C101A-XX supports preprogrammed multiplication factors of 2,3,4,5,6,8,10 and 12X.

### ORDERING INFORMATION

Part Number.	Package	Operating Temperature Range
ST49C101ACF8-01	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-03	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-05	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-06	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-07	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-08	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-09	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-10	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-13	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
ST49C101ACF8-15	8 Lead 150 Mil Jedec SOIC	0°C to 70°C
Consult Factory	Die	0°C to 70°C

Rev. 2.20

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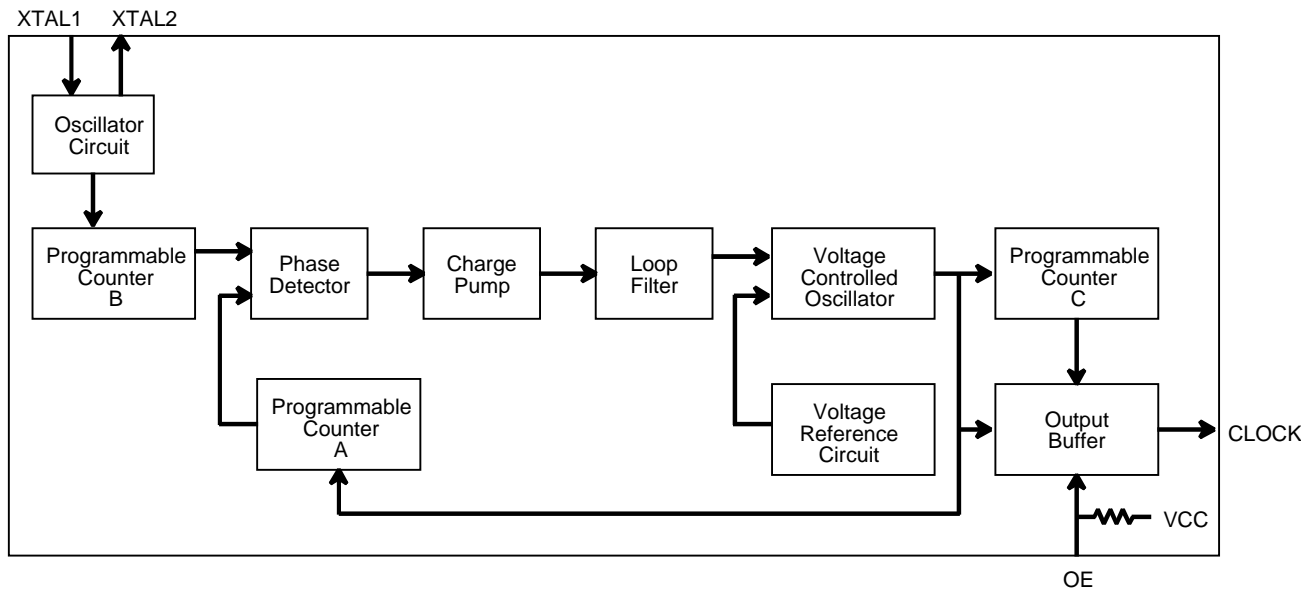
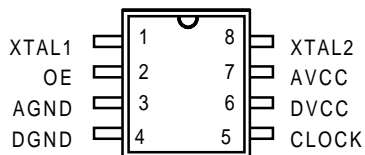


Figure 1. Block Diagram



8 Pin SOIC (Jedec, 0.150")

## PIN DESCRIPTION

Pin #	Symbol	Type	Description
1	XTAL1	I	<b>Crystal or External Clock Input.</b> A crystal can be connected to this pin and XTAL2 pin to generate internal phase locked loop reference clock. For external clock, XTAL2 is left open or used as buffered clock output.
2 <sup>1</sup>	OE	I	
3	AGND	O	<b>Analog Ground.</b>
4	DGND	O	<b>Digital Ground.</b>
5	CLOCK	O	<b>Programmed Output Clock.</b>
6	DV <sub>CC</sub>	I	<b>Positive Supply Voltage.</b> Single +5 or 3.3 volts.
7	AV <sub>CC</sub>	I	<b>Analog Supply Voltage.</b> Single +5 or 3.3 volts.
8	XTAL2	O	<b>Crystal Output.</b>

**Note:** <sup>1</sup>Has internal weak pull-up resistor

## MULTIPLICATION FACTOR AND OUTPUT FREQUENCY SELECTION

The ST49C101A-XX contains an analog phase locked loop (PLL) circuit with digital closed loop dividers and a final output divider to achieve the desired dividing ratios for the clock output. The preprogrammed multiplication factor and output frequency are shown on Table 1. The accuracy of the output frequency produced by the ST49C101A-XX depends on its input frequency and multiplication factor.

## APPLICATIONS

Two application examples are shown in Figure 2 and 3. Figure 2 shows a lower cost high frequency crystal oscillator circuit using the ST49C101-xx to increase the fundamental crystal frequency. The crystal Y1 is connected to XTAL1 and XTAL2 pins to use the internal oscillator circuit. The oscillator provides the reference clock to the PLL circuit for clock rate multiplication. Figure 3 shows a similar circuit using external clock input on XTAL1 pin instead.

If a sinewave is used for external clock, it may be necessary to AC couple the signal with a 0.047µF capacitor to XTAL1 pin so that the internal circuitry can establish the proper bias. Also, keep the peak-to-peak signal, at XTAL pin, above ground level (AGND) and below AVCC.

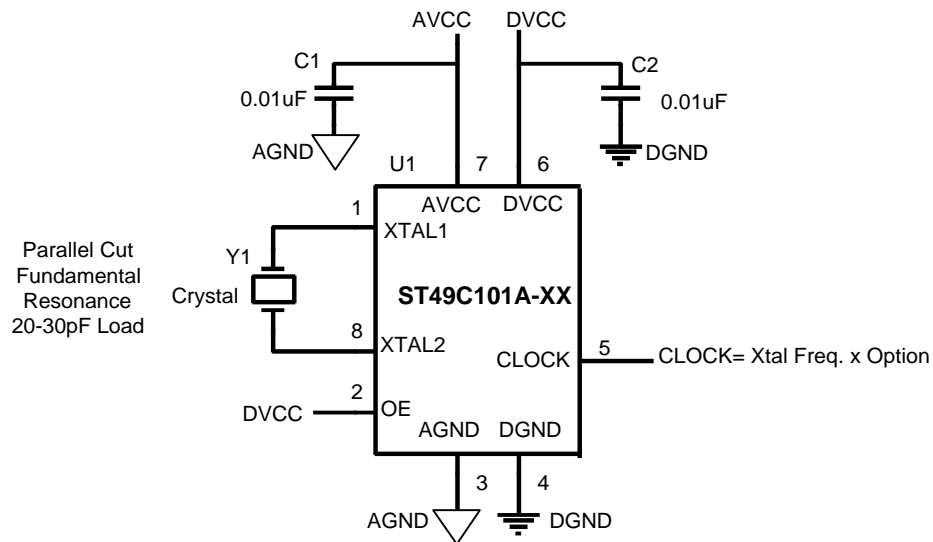
As a general board layout rule, it is recommended to use two 0.01µF bypass capacitors on DVCC and AVCC power supply pins, and put them as closely as possible to the chip.

Table 1. Preprogrammed Options

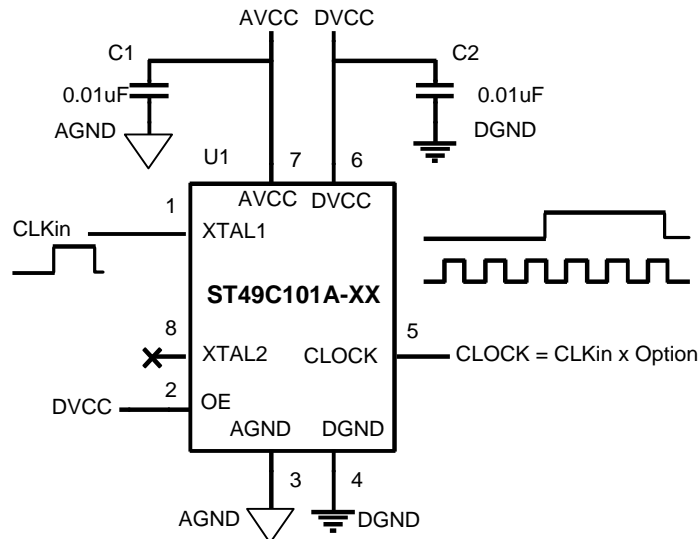
ST49C101A-XX	Factor	Max. Output Frequency <sup>1</sup>	VCC <sup>1</sup>
ST49C101A-01	12	200 MHz 140 MHz	5.0 V 3.3 V
ST49C101A-03	8	200 MHz 140 MHz	5.0 V 3.3 V
ST49C101A-05	6	200 MHz 140 MHz	5.0 V 3.3 V
ST49C101A-06	4	120 MHz	5.0 or 3.3 V
ST49C101A-07	3	80 MHz 70 MHz	5.0 V 3.3 V
ST49C101A-08	2	80 MHz 70 MHz	5.0 V 3.3 V
ST49C101A-09	5	200 MHz 140 MHz	5.0 V 3.3 V
ST49C101A-10	10	180 MHz	3.3 V
ST49C101A-13	8	180 MHz	3.3 V
ST49C101A-15	6	180 MHz	3.3 V

## Notes

<sup>1</sup>See AC electrical characteristics for maximum operating frequency.



**Figure 2. High Frequency Crystal Oscillator Using a Crystal for Reference.**



**Figure 3. High Frequency Clock Rate Multiplication Using External Clock.**

## DC ELECTRICAL CHARACTERISTICS

Test Conditions:  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = 5.0\text{V} + 10\%$ , Operating Temperature Range  $0^\circ\text{C}$  to  $70^\circ\text{C}$  Unless Otherwise Specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
$V_{IL}$	Input Low Level			0.8	V	
$V_{IH}$	Input High Level	2.0			V	
$V_{OL}$	Output Low Level			0.5	V	$I_{OL} = 8.0\text{ mA}$
$V_{OH}$	Output High Level	2.8			V	$I_{OH} = 8.0\text{ mA}$
$I_{IL}$	Input Low Current			-100	$\mu\text{A}$	OE Pin only
$I_{IH}$	Input High Current			1	$\mu\text{A}$	$V_{IN} = V_{CC}$ , OE Pin only
$I_{CC}$	Operating Current		35	50	mA	No Load. CLOCK=100MHz
$R_{IN}$	Input Pull-up Resistance	75	110	155	k $\Omega$	

## AC ELECTRICAL CHARACTERISTICS

Test Conditions:  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = 5.0\text{V} + 10\%$ , Operating Temperature Range  $0^\circ\text{C}$  to  $70^\circ\text{C}$  Unless Otherwise Specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
T1, T2	CLOCK Rise/Fall Time		1.5	3	ns	Load=30 pF, $0.2 V_{CC} - 0.8 V_{CC}$
$\frac{T4}{T4 + T5}$	Duty Cycle	45	50	55	%	$V_{CC}/2$ Switch Point Up To 100MHz, Load = 20pF
$\frac{T4}{T4 + T5}$	Duty Cycle	40	50	60	%	$V_{CC}/2$ Switch Point 100-150MHz, 95 $\Omega$ (AC Terminated)
T3	Jitter 1 Sigma		$\pm 0.4$	$\pm 1$	%	Of Period
T3	Jitter Absolute		$\pm 1$	$\pm 3$	%	Of Period
$T_{IN}$	Input Reference Frequency	12	20	30	MHz	
$T_{OUT}$	Output Frequency	50		200	MHz	ST49C101A-01
		50		200	MHz	ST49C101A-03
		50		200	MHz	ST49C101A-05
		50		120	MHz	ST49C101A-06
		25		80	MHz	ST49C101A-07
		25		80	MHz	ST49C101A-08
		50		200	MHz	ST49C101A-09

## DCELECTRICAL CHARACTERISTICS

Test Conditions:  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3.3\text{V} \pm 10\%$ , Operating Temperature Range  $0^\circ\text{C}$  to  $70^\circ\text{C}$  Unless Otherwise Specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
$V_{IL}$	Input Low Level			0.8	V	
$V_{IH}$	Input High Level	2.0			V	
$V_{OL}$	Output Low Level			0.5	V	$I_{OL} = 4.0\text{mA}$
$V_{OH}$	Output High Level	2.0			V	$I_{OH} = 4.0\text{mA}$
$I_{IL}$	Input Low Current			-100	$\mu\text{A}$	OE Pin Only
$I_{IH}$	Input High Current			1	$\mu\text{A}$	$V_{IN} = V_{CC}$ , OE Pin only
$I_{CC}$	Operating Current		22	40	mA	No Load. CLOCK=100MHz
$R_{IN}$	Input Pull-up Resistance	75	110	155	k $\Omega$	

## ACELECTRICAL CHARACTERISTICS

Test Conditions:  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3.3\text{V} \pm 10\%$ , Operating Temperature Range  $0^\circ\text{C}$  to  $70^\circ\text{C}$  Unless Otherwise Specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
T1, T2	CLOCK Rise/Fall Time		2	4	ns	Load = 30 pF, $0.2 V_{CC} - 0.8 V_{CC}$
$\frac{T4}{T4+T5}$	Duty Cycle	45	50	55	%	$V_{CC}/2$ switch point up to 100MHz, Load = 30 pF
$\frac{T4}{T4+T5}$	Duty Cycle	40	50	60	%	$V_{CC}/2$ switch point 100-150MHz, 95 $\Omega$ (AC Terminated)
T3	Jitter 1 Sigma		$\pm 0.4$	$\pm 1$	%	Of Period
T3	Jitter Absolute		$\pm 1$	$\pm 3$	%	Of Period
$T_{IN}$	Input Reference Frequency	12	20	30	MHz	
$T_{OUT}$	Output Frequency	50		140	MHz	ST49C101A-01
		50		140	MHz	ST49C101A-03
		50		140	MHz	ST49C101A-05
		50		150	MHz	ST49C101A-05 at $V_{CC} = 3.13\text{V}$ min.
		50		120	MHz	ST49C101A-06
		25		70	MHz	ST49C101A-07
		25		70	MHz	ST49C101A-08
		50		140	MHz	ST49C101A-09
		25		180	MHz	ST49C101A-10 at $V_{CC} = 3.13\text{V}$ min.
		25		180	MHz	ST49C101A-13 at $V_{CC} = 3.13\text{V}$ min.
		25		180	MHz	ST49C101A-15 at $V_{CC} = 3.13\text{V}$ min.

## ABSOLUTE MAXIMUM RATINGS

Supply Range . . . . . 7 V  
 Voltage at Any Pin. . . . . GND-0.3V to  $V_{CC} + 0.3V$   
 Operating Temperature . . . . . 0°C to +70°C

Storage Temperature . . . . . -40°C to +150°C  
 Package Dissipation . . . . . 500mW

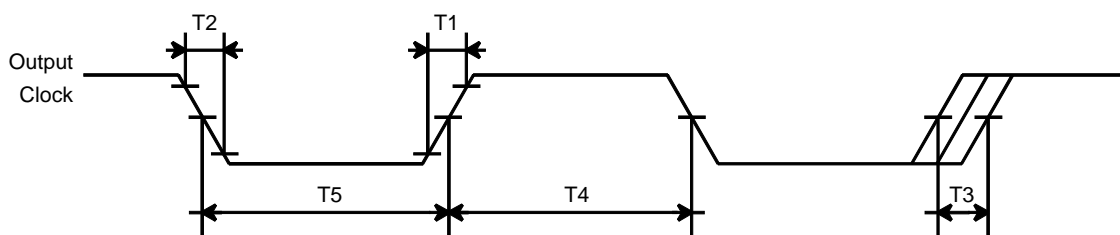
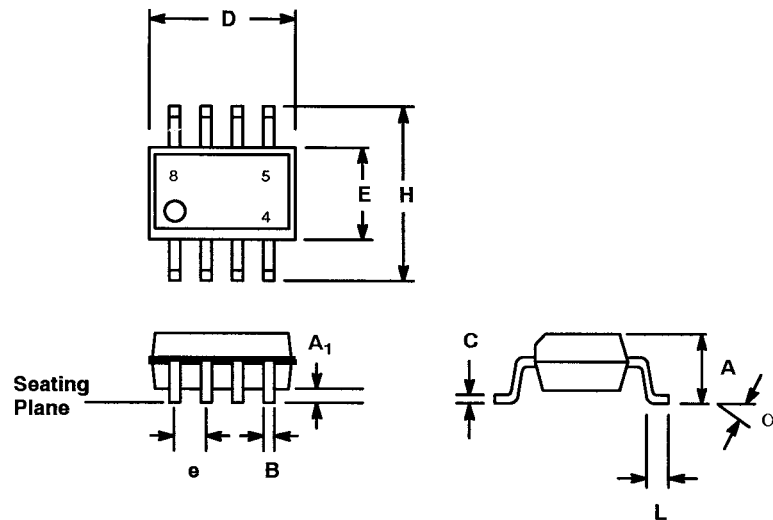


Figure 4. Timing Diagram



**8 LEAD SMALL OUTLINE  
(150 MIL JEDEC SOIC)**

*Rev. 1.00*



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A <sub>1</sub>	0.004	0.010	0.10	0.25
B	0.013	0.020	0.33	0.51
C	0.007	0.010	0.19	0.25
D	0.189	0.197	4.80	5.00
E	0.150	0.157	3.80	4.00
e	0.050 BSC		1.27 BSC	
H	0.228	0.244	5.80	6.20
L	0.016	0.050	0.40	1.27
α	0°	8°	0°	8°

*Note: The control dimension is the millimeter column*

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Datasheet January 1999

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